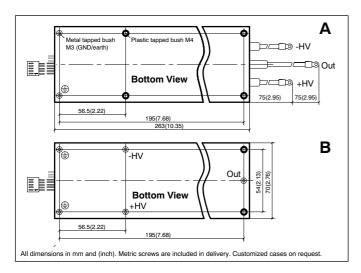
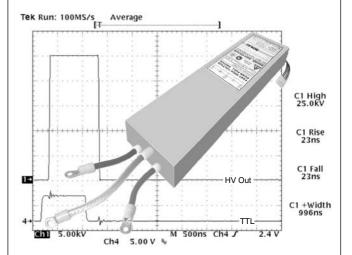
FAST HIGH VOLTAGE TRANSISTOR SWITCHES

The switching modules of the series HTS-GSM consist of two identical MOSFET switching paths, that form a so-called half bridge circuit respectively push-pull circuit. Both switching paths are controlled by a common driver, which also provides a logic signal negation for one of the switches. The switches are mutually passively locked, so that a short in the bridge is excluded under all circumstances, even then, if the control input is disturbed by electromagnetic interferences (due to bad EMC design, for example). Especially in pulse generator applications with capacitive load, the push-pull principle has considerable advantages in comparision with the conventional circuitry using a single-switch with working resistor. Push-pull circuits do not require large energy storage capacitors for a low pulse droop and, because there are no working resistor power losses, the efficiency of a push-pull pulser is excellent regardless to pulse width, frequency and duty cycle. The pulsers draw only currents for charging the connected load capacitance. Thanks to an extremely precise timing of the switches, there are also almost no cross currents in the bridge, except peak charging currents of the switch natural capacitances.

The switches are controlled by positive going signals of 3 to 10 Volts amplitude. Fault conditions as overfrequency, thermal overload (long-term overload) and incorrect auxilliary supply set the switching path A in off-state and the switching path B in onstate. Faults are indicated as a "L" signal at the fault signal output. Without 5VDC supply both switching paths (A and B) are in off-state. That means, without 5VDC the output potential could be undefined, if the HV is still applied. To ensure a defined high voltage output potential in such cases, pull-up or pull-down resistors must be connected to the output. For further design recommendations please refer to the general instructions.



HTS 161-06-GSM 2x16kV / 60A HTS 301-03-GSM 2x30kV / 30A

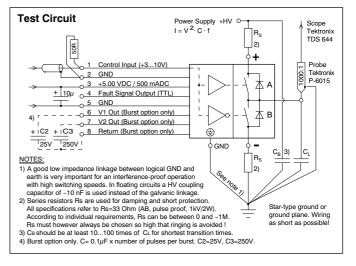


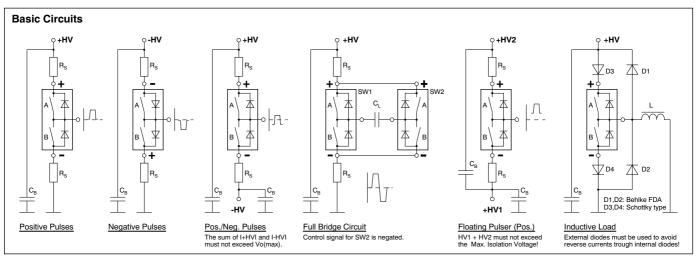
- Fast transition times, rise time and fall time ~20 ns
- Variable pulse width from 200 ns to infinity
- No pulse droop and very low ripple on the pulse top
- No working resistor power, small buffer capacitors

PUSH-PULL

- Patented -Made in Germany









TECHNICAL DATA

Specification	Symbol	Condition / Comment			161-06-GSM	301-03-GSM	Unit	
Maximum Operating Voltage	$V_{O(max)}$	I _{off} < 10 σADC				2 x 16	2 x 30	kVDC
Minimum Operating Voltage	$V_{O(min)}$	Increased transition times below 0.1 x V _{O(max)}				0		kVDC
Typical Breakdown Voltage	V_{br}	Static voltage, $I_{off} > 1 \text{ mADC}$, , $T_{case} = 70 \text{ °C}$				2 x 18	2 x 36	kVDC
Galvanic Isolation Voltage	VI	Standard plas	andard plastic case (see note 1)			25	40	
		Option 08A (Pigtail version only, see drawing A)			40	-		
		Option 08B (Pigtail version only, see drawing A)			80	80	kVDC	
Maximum Peak Current	I _{P(max)}	$T_{case} = 25$ °C $t_p < 10 \mu s$, duty cycle $< 1\%$			2 x 60	2 x 30	ADC	
Max. Continuous Load Current	IL	T _{case} = 25°C	Standa	rd plastic ca	ase (see note 1)	2 x 0.7	2 x 0.33	
		$T_{fin} = 25$ °C			hermal conductivity	2 x 0.86	2 x 0.41	
			Opt. 04	, cooling fir	ns (air >4m/s)	2 x 2.2	2 x 1.05	ADC
Static On-Resistance	R _{stat}	$T_{case} = 25$ °C				2 x 18	2 x 72	
			1.0 x I _P	(max)		2 x 40	2 x 180	ô
Maximum Off-State Current	I _{off}	$0.8xV_{O,}$ T_{case} = 2570°C, reduced I_{off} on request			10		σADC	
Propagation Delay Time	t _d	Resistive Load			190		ns	
Typical Output Transition Time	t _{r,} t _f	0.8 x V _O		$R_S = 33 \hat{o}$	$C_L = 10pF$	10	20	
(Rise Time & Fall Time)		10-90%		$R_S = 33 \hat{o}$	$C_L = 50pF$	15	35	
				$R_S = 33 \hat{o}$	$C_L = 100pF$	17	50	
				$R_S = 33 \hat{o}$	$C_L = 200pF$	25	90	
1				$R_S = 22 \hat{o}$	$C_L = 1000pF$	60	230	ns
Minimum Output Pulse Width	t _{p(min)}	Reduced output pulse width on request.				20	00	ns
Maximum Output Pulse Width	t _{p(max)}					No limitation, up to ¬		
Minimum Pulse Spacing	t _{ps(min)}	(Switch recovery time)				400		ns
Typical Output Pulse Jitter	t _j	V _{aux} =5.0 VDC Fixed switching frequency, >2kHz			0.1			
	'	$V_{tr} = 5.0 \text{ VDC}$				5	j	ns
Max. Continuous Switching	f _(max)	Please note possible P _{d(max)} limitations.						
Frequency		Increased switching frequency on request.				2		kHz
Maximum Burst Frequency	f _{b(max)}	Use option 01 for >10 pulses per 20µs burst				2.5		MHz
Maximum Continuous Power	P _{d(max)}	T _{case} = 25°C Standard plastic case		case (see note 1)	2 x	20		
Dissipation		$T_{fin} = 25$ °C	Opt. 0	03, incr. ther	mal conductivity	2 x	30	
			Opt.	04, air spee	ed >4m/s (s. note 2)	2 x 2	200	Watts
Linear Derating		Above 25 °C Standard plastic case		2 x 0.44				
			Opt.0	3, incr. therr	mal conductivity	2 x (0.66	
		Opt. 04, air speed >4m/s		2 x 4.44		W/K		
Operating Temperature Range	To	·			-4070		°C	
Typical Natural Capacitance	C _N	Capacitance	betweer	the	0.1 x V _{O(max)}	< 9	90	
		terminals of <u>one</u> switch path 0.8 x V _{O(max)}			< 30		pF	
Typical Coupling Capacitance	C _c	Both switches against ground respectively control				< 30		pF
Reverse Recovery Time	t _{rrc}	Important Note: Due to the high t_{rrc} of the parasitic diodes any						
of the intrinsic diodes		current reversal must be avoided! Unclamped inductive load or high stray inductance of wiring may cause a short circuit in the bridge.						
(parasitic MOSFET diodes)		Danger of irreparable damage! Use serial resistors, snubbers or fast free-wheeling diode networks to avoid any current reversal.				5001000		ns
Auxiliary Supply Voltage	V _{aux}	Stabilized to ∂ 5%				5.00		VDC
Auxiliary Supply Current	l _{aux}	@f _{max} , (Limitation of approx. 1 A recommended)				600		mADC
Control Signal	V _{tr}	>3VDC recommended for low jitter				310		VDC
Fault Signal Output		Short circuit proof, source/sink Ready = High			⁻ 4.0			
		current max.	10 mA		Fault = Low	m0	.8	VDC
Dimensions	LxWxH	Standard case (Without pigtails & opt. cooling fins)				263x70x35		mm³
Weight		Standard plastic case With option 04 (cooling fins in standard size)			80	00		
					14	50	g	

Notes:

boards is preferred in high speed circuits with transition times in the order of 10 to 20 ns or in case of critical EMC aspects.

2) Cooling fins are not recommended if the HTS 301-03-GSM shall be operated in air above 20 kVDC. No limitations if operated in oil. Please consult factory for further oil cooling information.

Ordering Information

HTS 161-06-GSM Push-pull transistor switch Option 05 High power metal case (on request) HTS 301-03-GSM Push-pull transistor switch Option 06 Printed circuit board version of HTS 301-03-GSM. 40kV isolation for HTS 161-06-GSM (pigtail version "A" only) Option 01 Option 08A High frequency burst Option 03 Increased thermal conductivity Option 08B 80kV isolation (pigtail version "A" only) Option 04 Non-isolated cooling fins (oil immersion for Vo >20 kV)

¹⁾ The standard case is "A" for the HTS 301-03-GSM and "B" for the HTS 161-06-GSM. Please refer to the drawing overleaf. Version "B" is optionally also available for the HTS 301-03-GSM (option 06) but only in connection with additional isolation measures (e.g. oil immersion) or in case of operating voltages less than 20 kVDC. The version "B" for attachment on printed circuit boards is preferred in high speed circuits with transition times in the order of 10 to 20 ps or in case of critical EMC aspects.